

Stability Enhancement of Silver Nanowire Networks with Conformal ZnO Coatings Deposited by Atmospheric Pressure Spatial Atomic Layer Deposition

Viet Huong Nguyen, Dorina Papanastasiou, Thomas Sannicolo, Sara Aghazadehchors, Afzal Khan, Carmen Jiménez, Ngoc Duy Nguyen, Daniel Bellet, **David Muñoz-Rojas**

david.munoz-rojas@grenoble-inp.fr

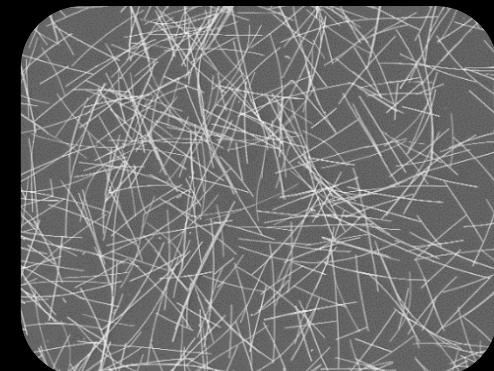
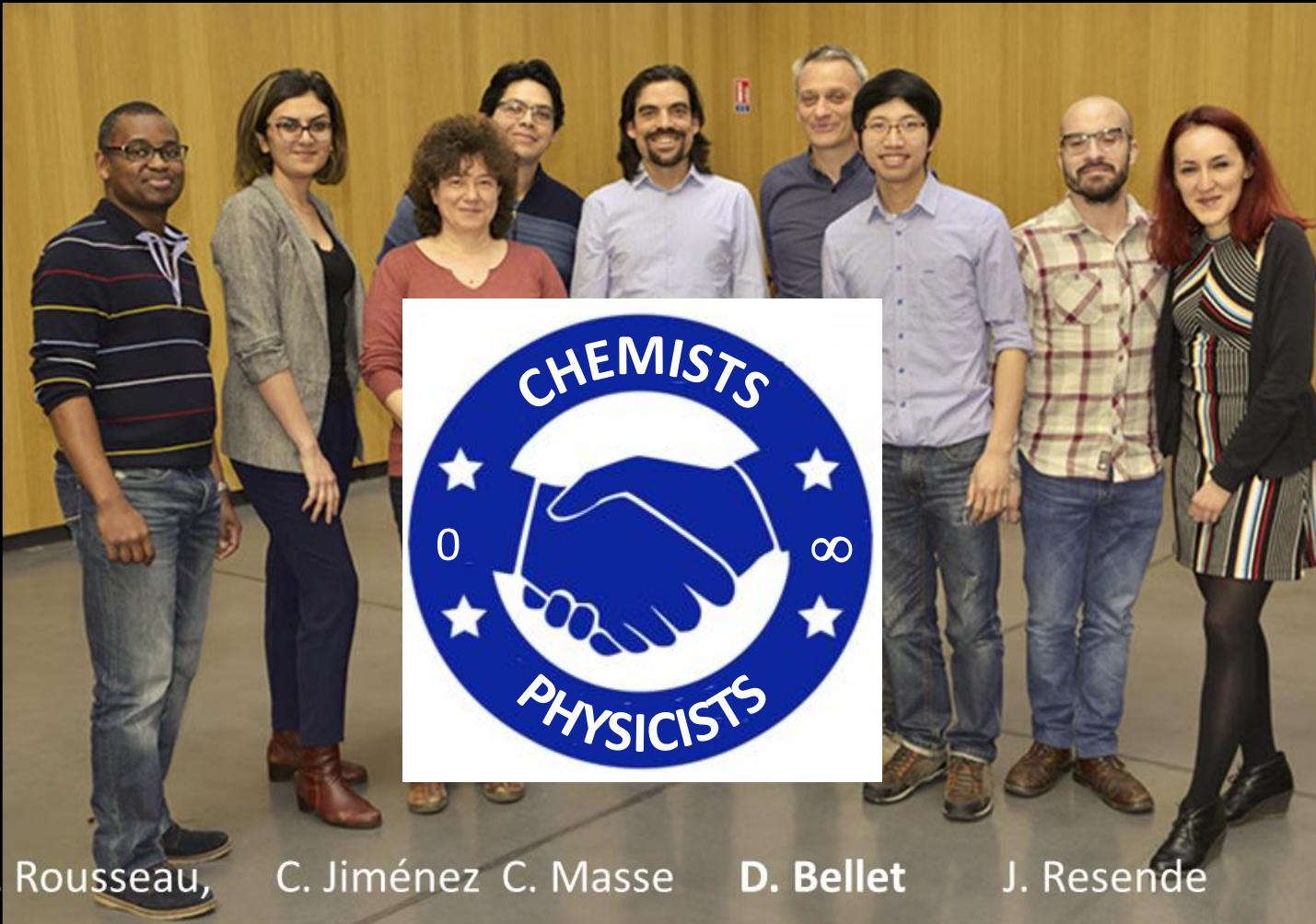
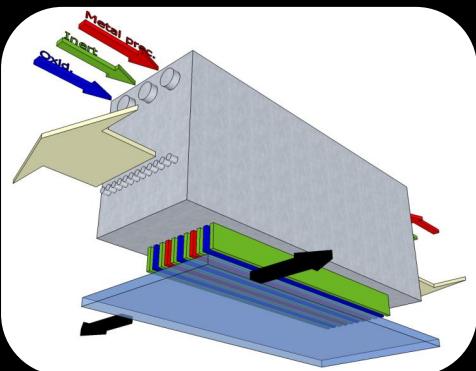
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Laboratoire des Matériaux et du Génie Physique (Grenoble-INP/CNRS)

EuroCVD-BalticALD 2019, 27th June, Luxembourg



SALD Team + AgNWs Team = improved TCM



Transparent conductive materials

*Optoelectronic
devices*



Alternative transparent
electrodes are needed...

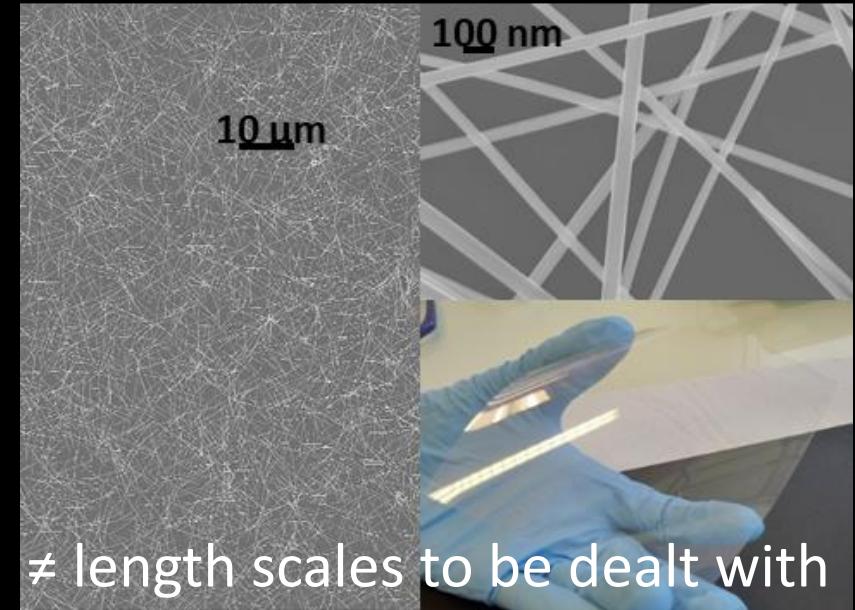
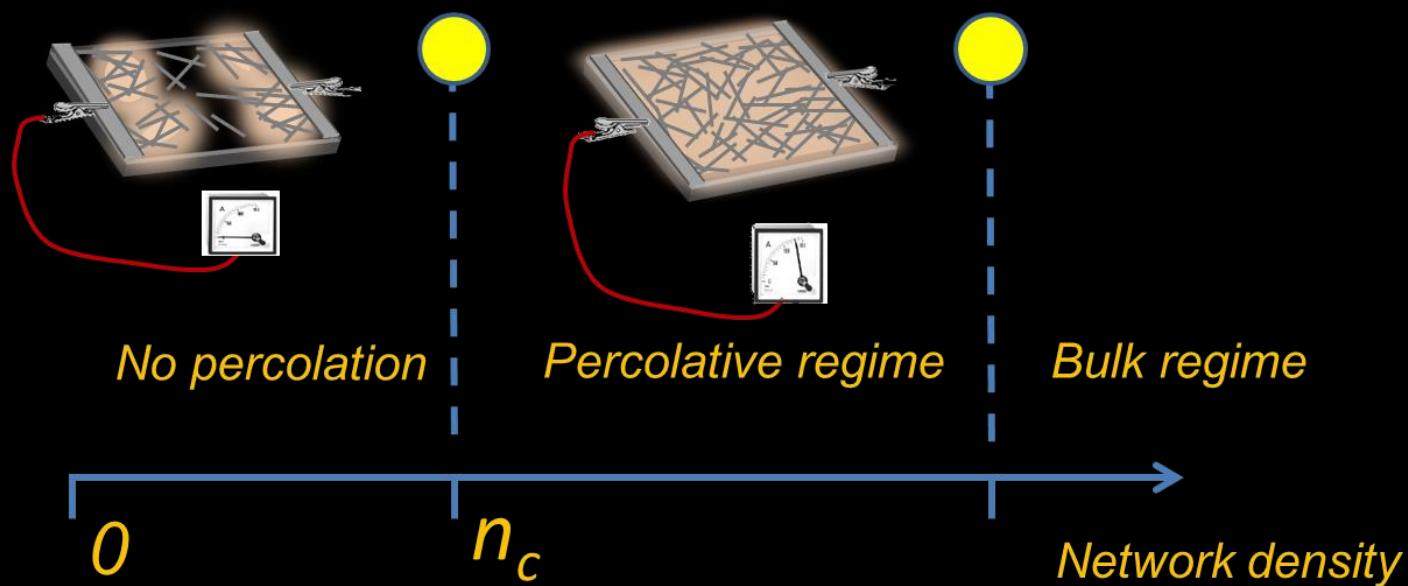
*Transparent
heaters*

Transparent heater for
defrosting window

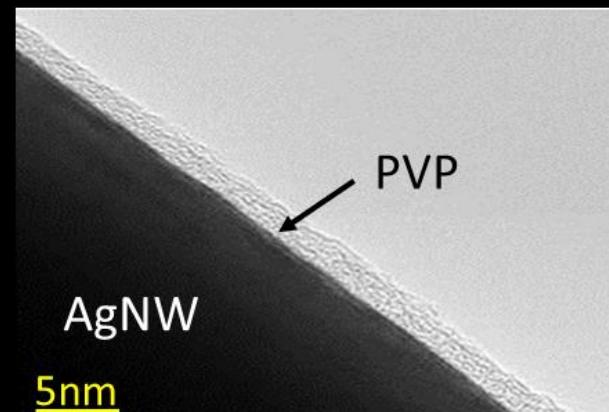
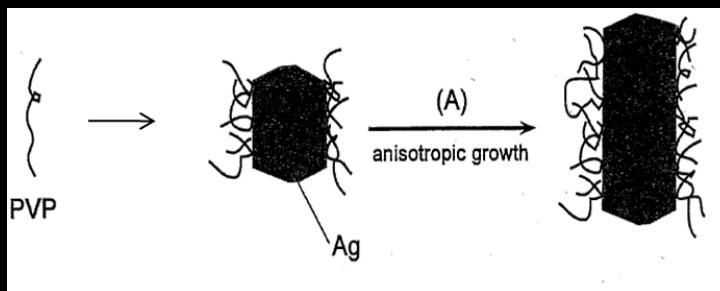
- *Manganese scarcity*
- *Brittleness*



AgNW Networks as alternative TCM

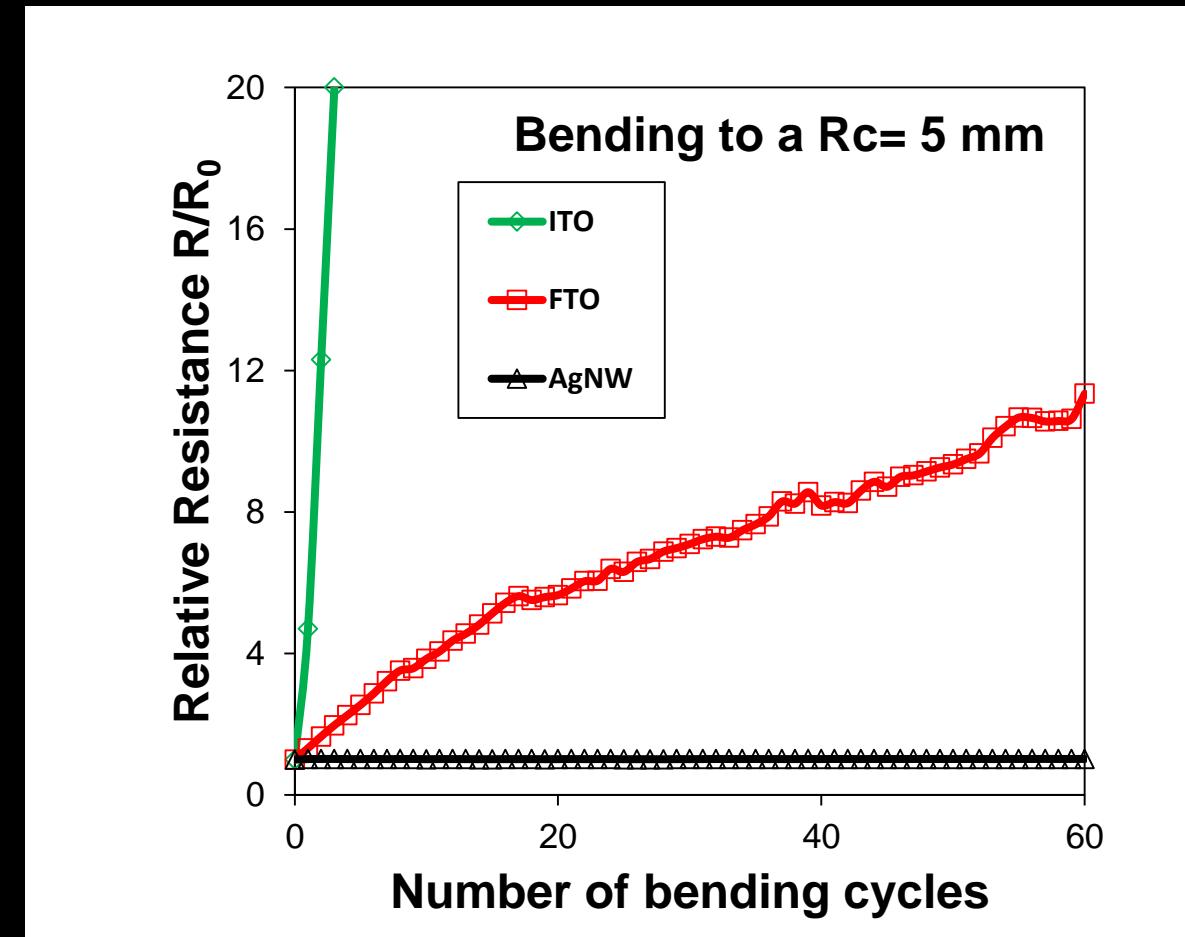
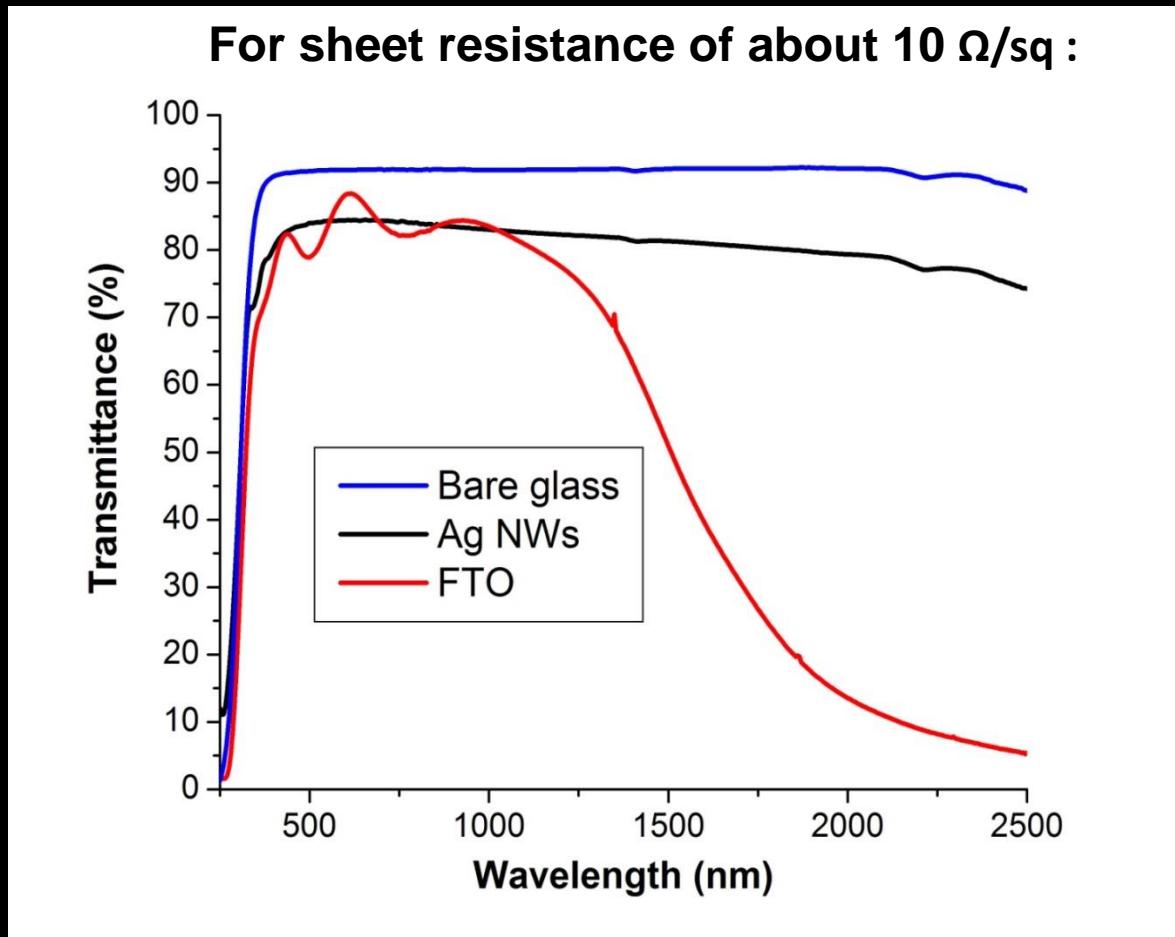


Ag NWs synthesized by the polyol method

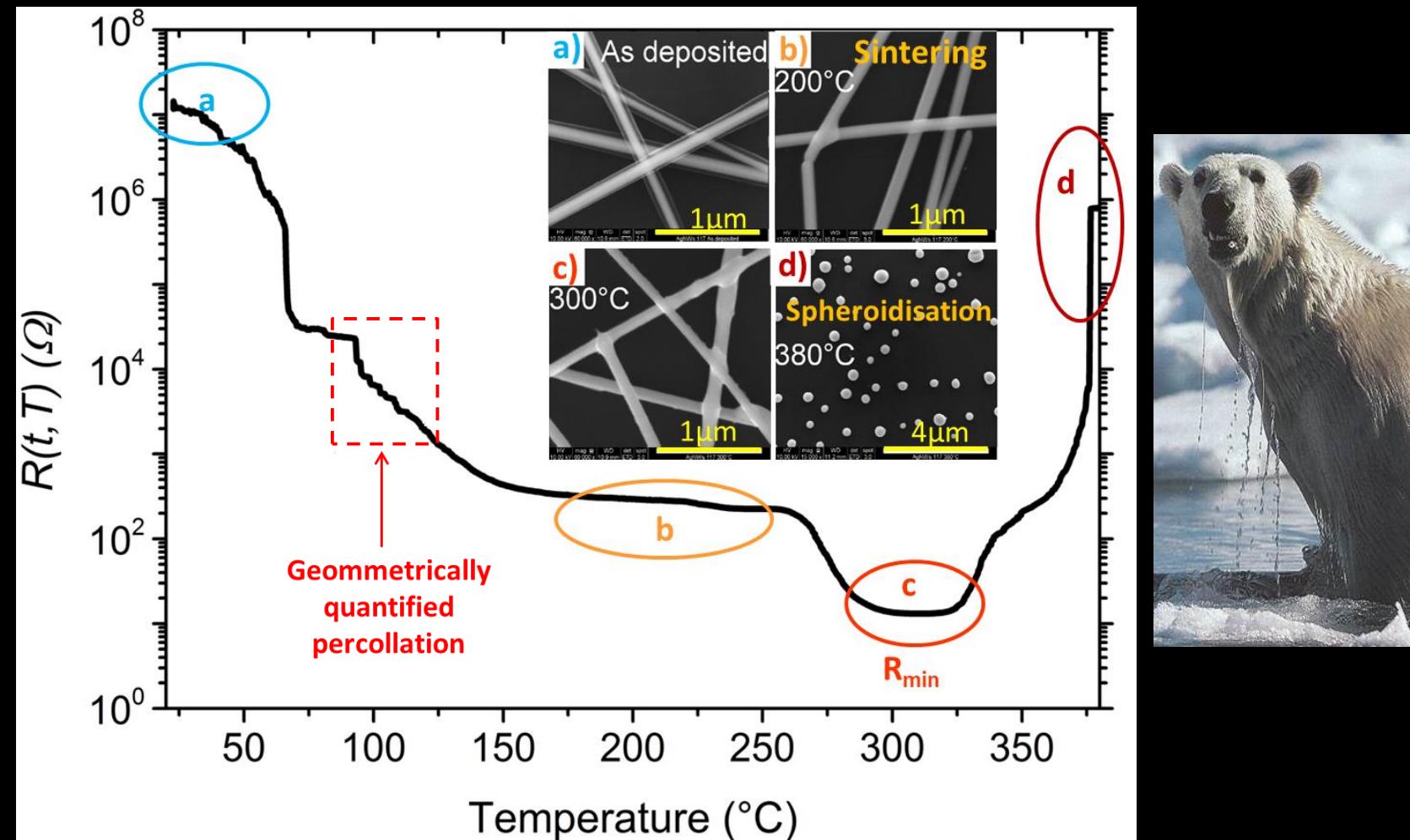
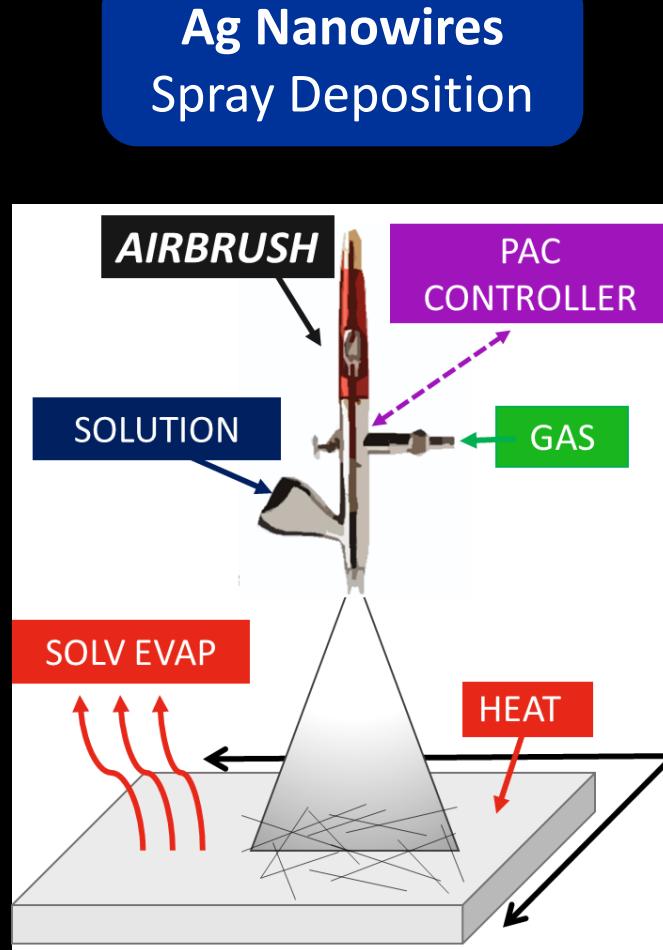


AgNW Networks as alternative TCM

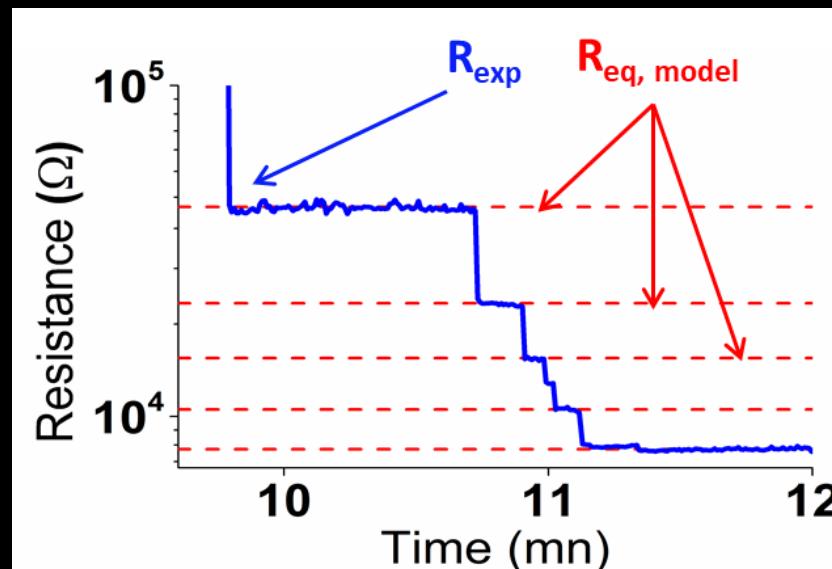
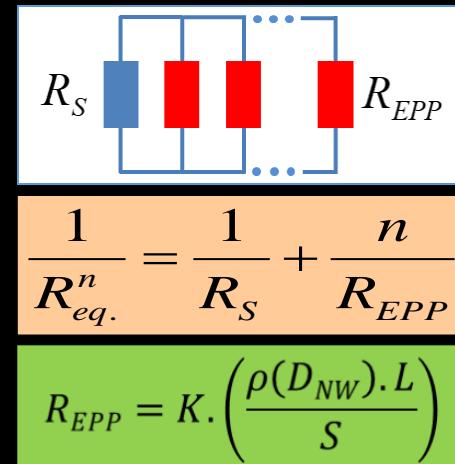
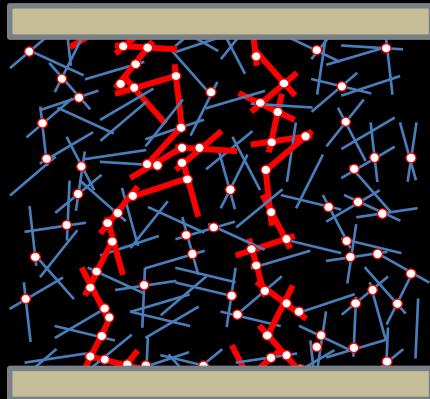
More transparent to IR than TCO and more flexible



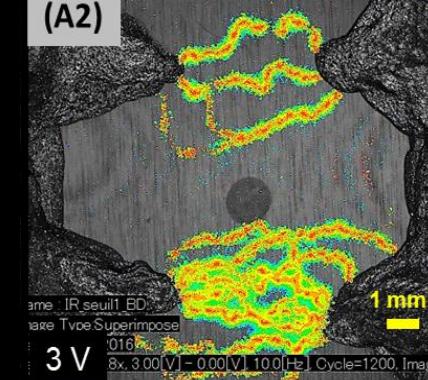
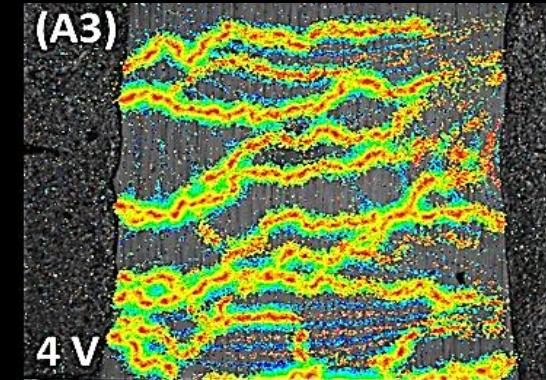
Deposition and optimisation of Ag NW networks



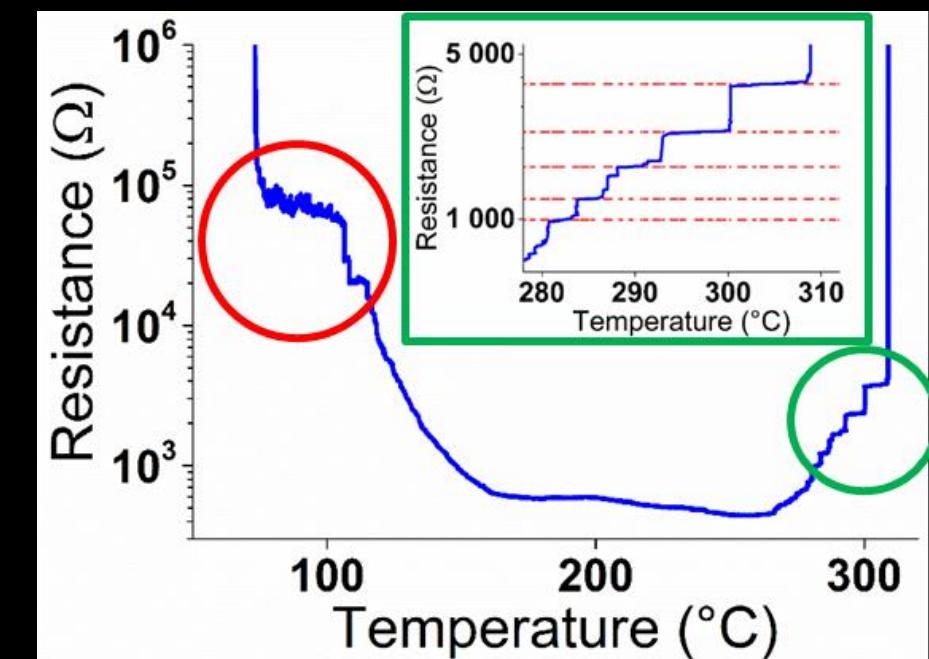
Quatized percolation and antipercolation



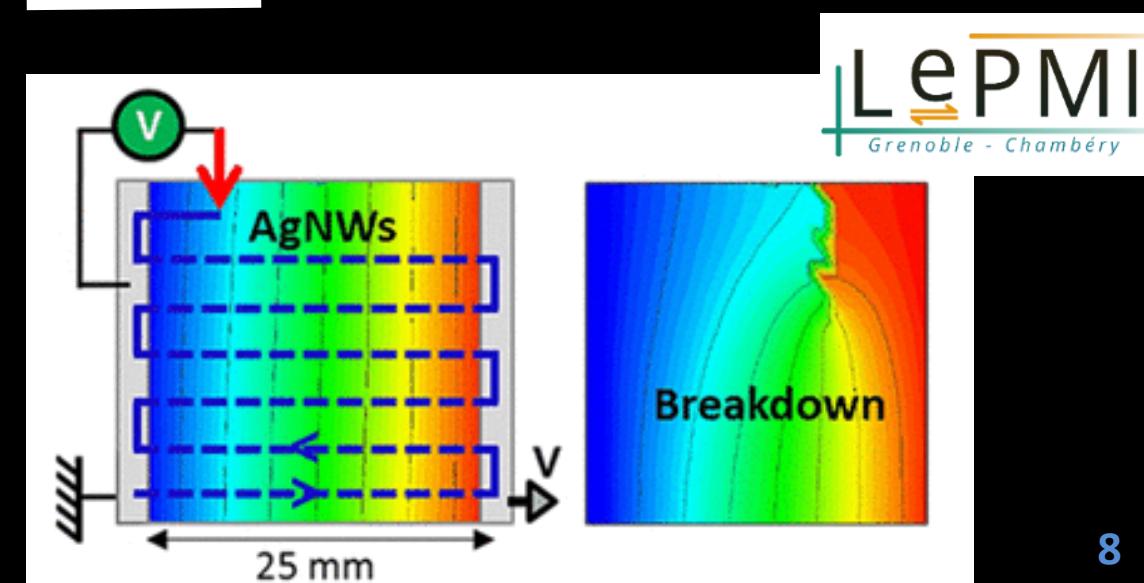
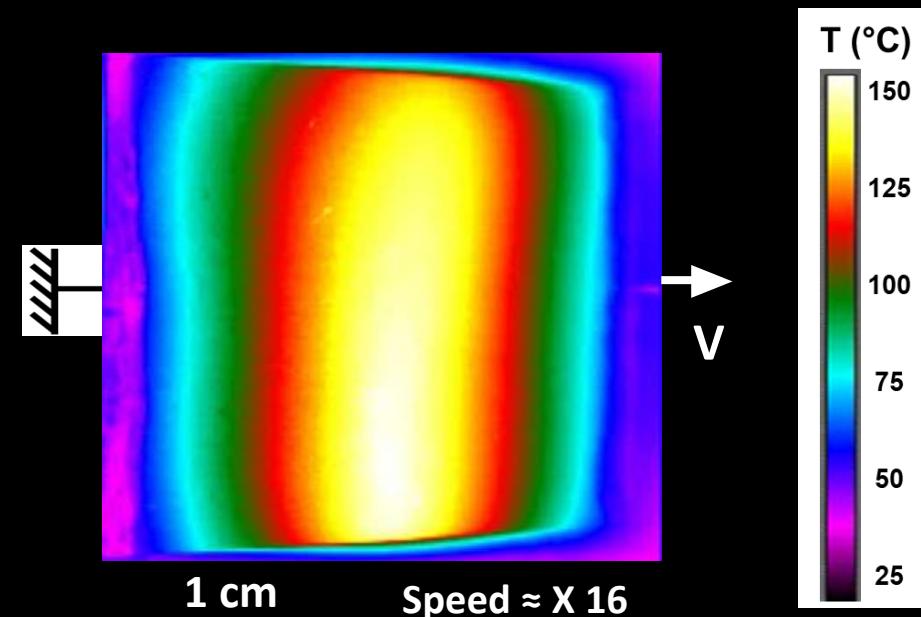
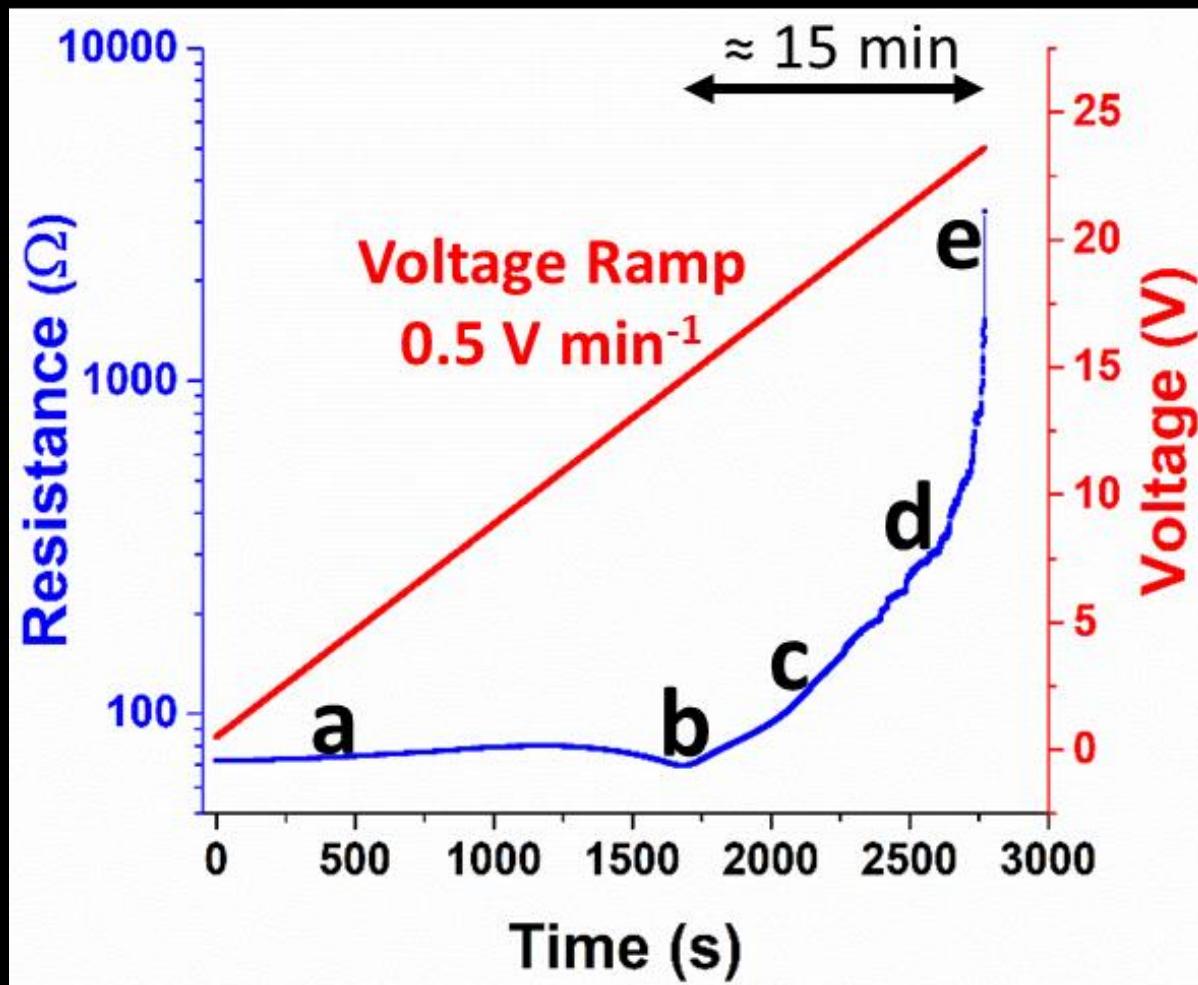
Lock-in IR Thermography



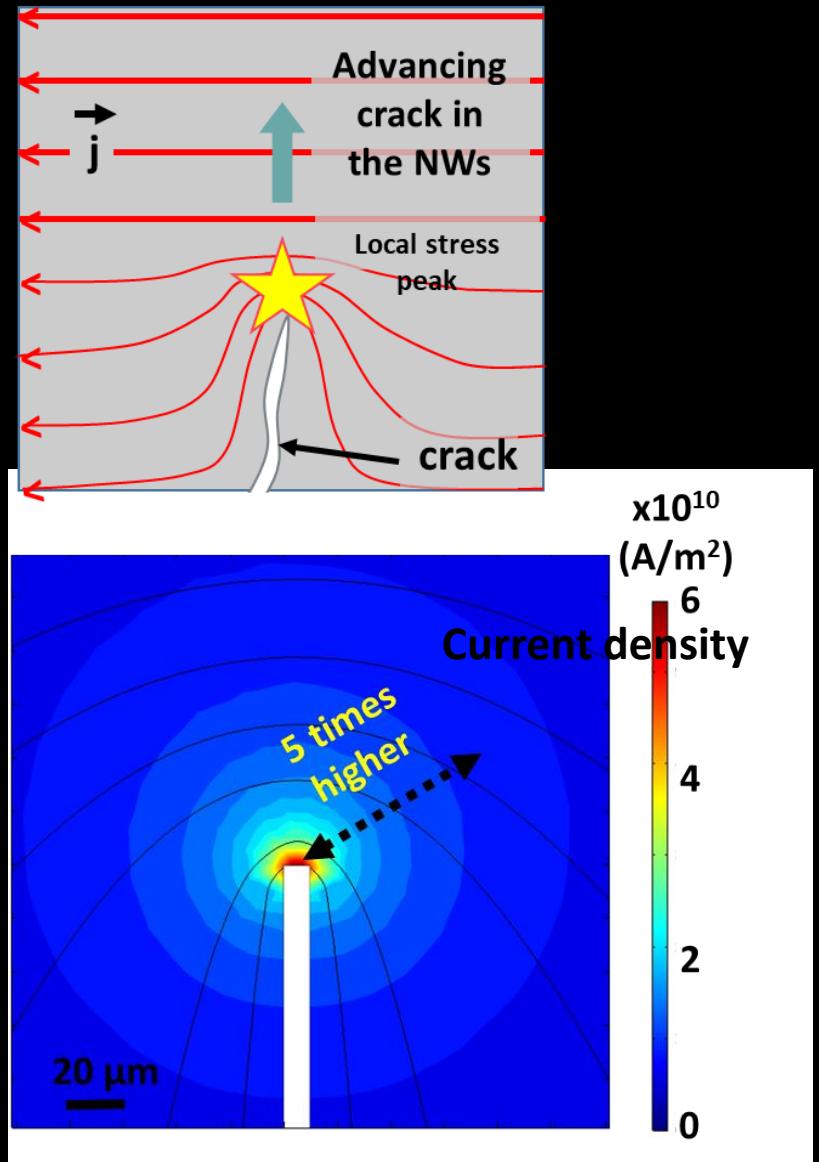
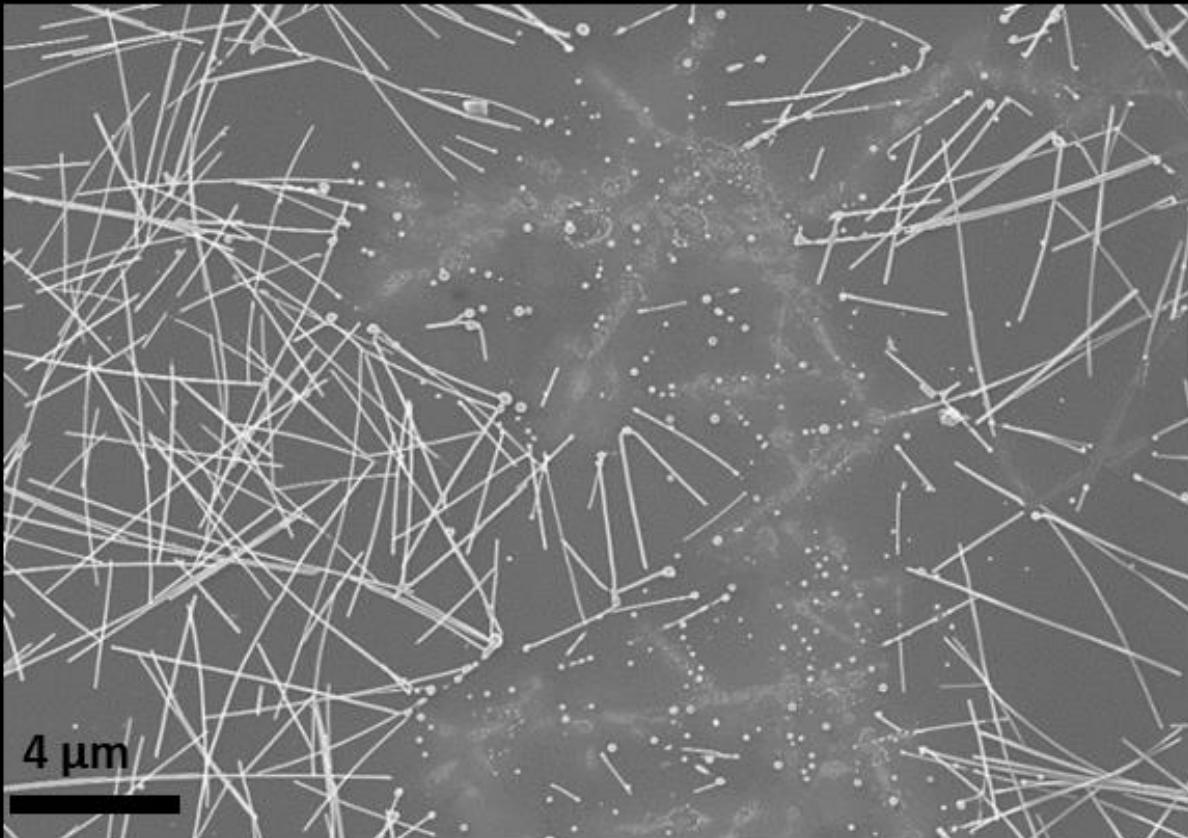
DE LA RECHERCHE À L'INDUSTRIE
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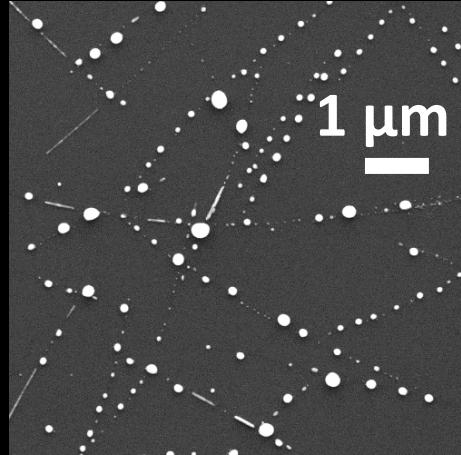
Electrical stress also degrades AgNW networks



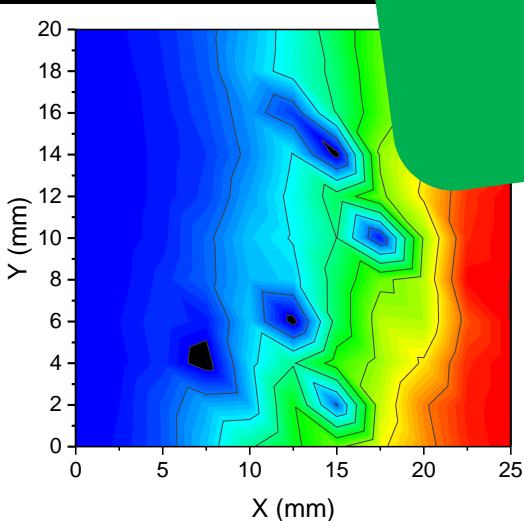
Electrical stress also degrades AgNW networks



Drawbacks of AgNW networks



Electrical Map

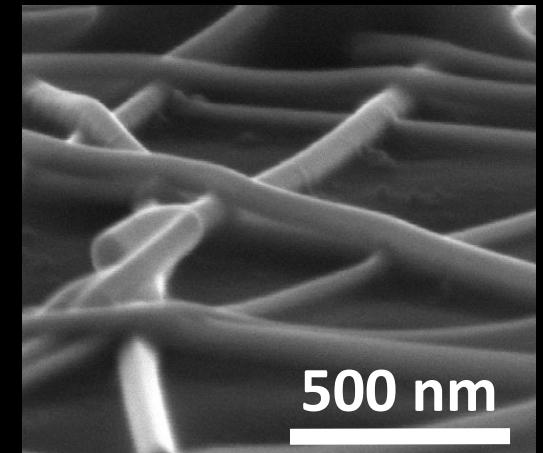
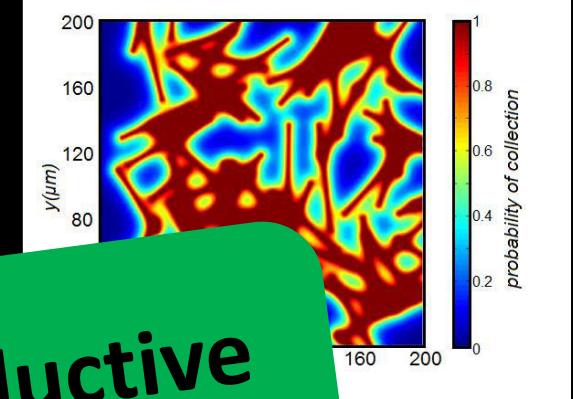


- Low thermal and electrical conductivity

Possible solution: Transparent Conductive Nanocomposites

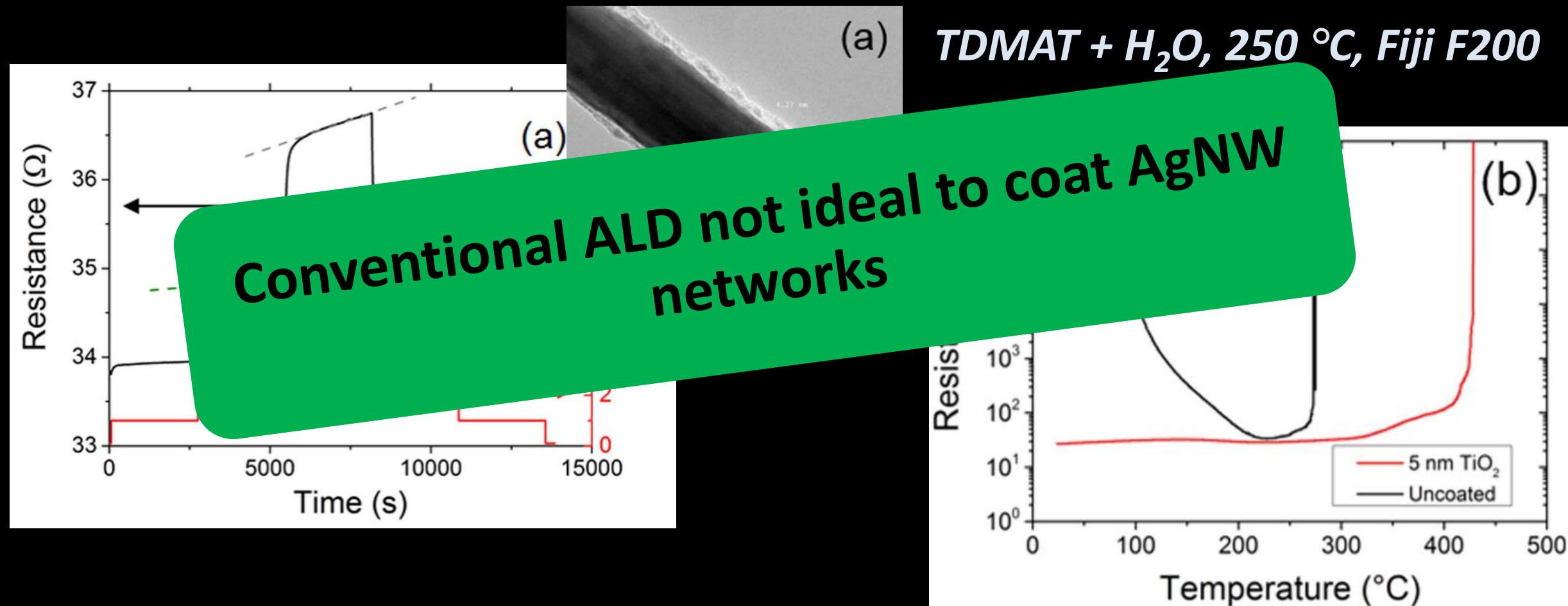
- Good adhesion to the substrate

Probability of charge collection



AgNWs/oxide composites

Coating AgNW networks with a thin layer of oxide improves stability



Atmospheric Pressure Spatial ALD (AP-SALD)

Up to 100 times faster, atmospheric pressure, even open-air

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Speeding up the unique assets of atomic layer deposition

D. Muñoz-Rojas ^{a,*}, T. Maindron ^b, A. Esteve ^c, F. Piallat ^d, J.C.S. Kools ^e, J.-M. Decamps ^f

^a Univ. Grenoble Alpes, CNRS, Grenoble INP, IMCD, F-38000 Grenoble, France



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Spatial atmospheric atomic layer deposition: a new laboratory and industrial tool for low-cost photovoltaics

Cite this: DOI: 10.1039/c3mh00136a

David Muñoz-Rojas^{*abc} and Judith MacManus-Driscoll^c

Spatial Atomic Layer Deposition

David Muñoz-Rojas, Viet Huong Nguyen, César Masse de la Huerta, Carmen Jiménez and Daniel Bellet

Additional information is available at the end of the chapter

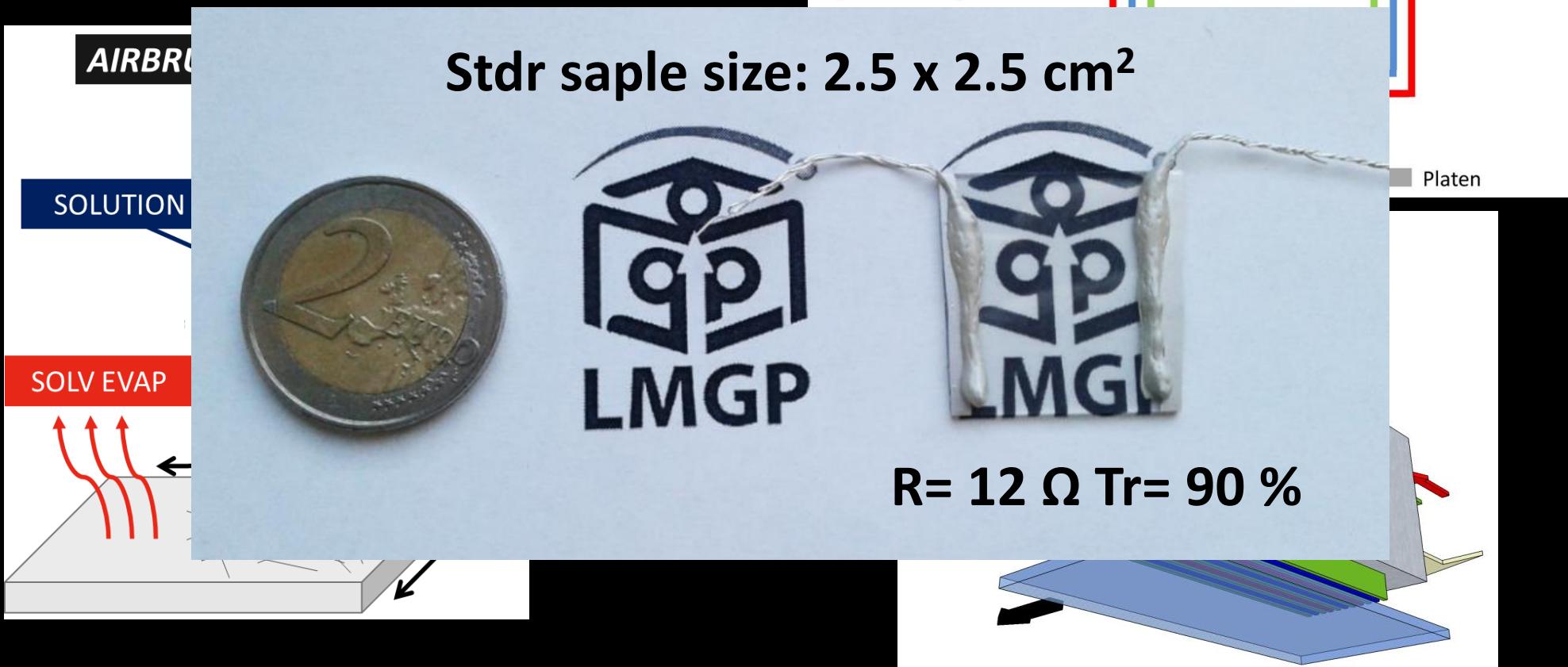
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Atmospheric open-air processing

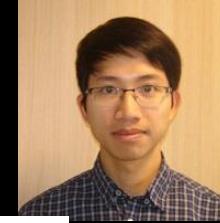
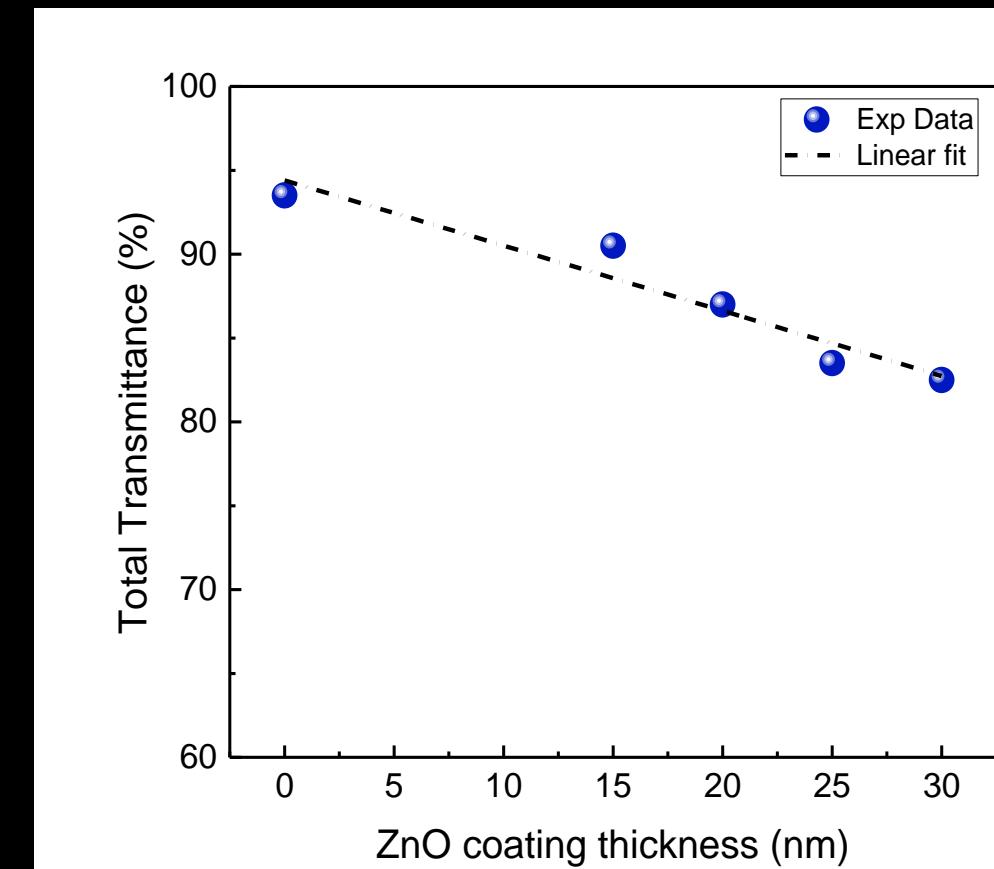
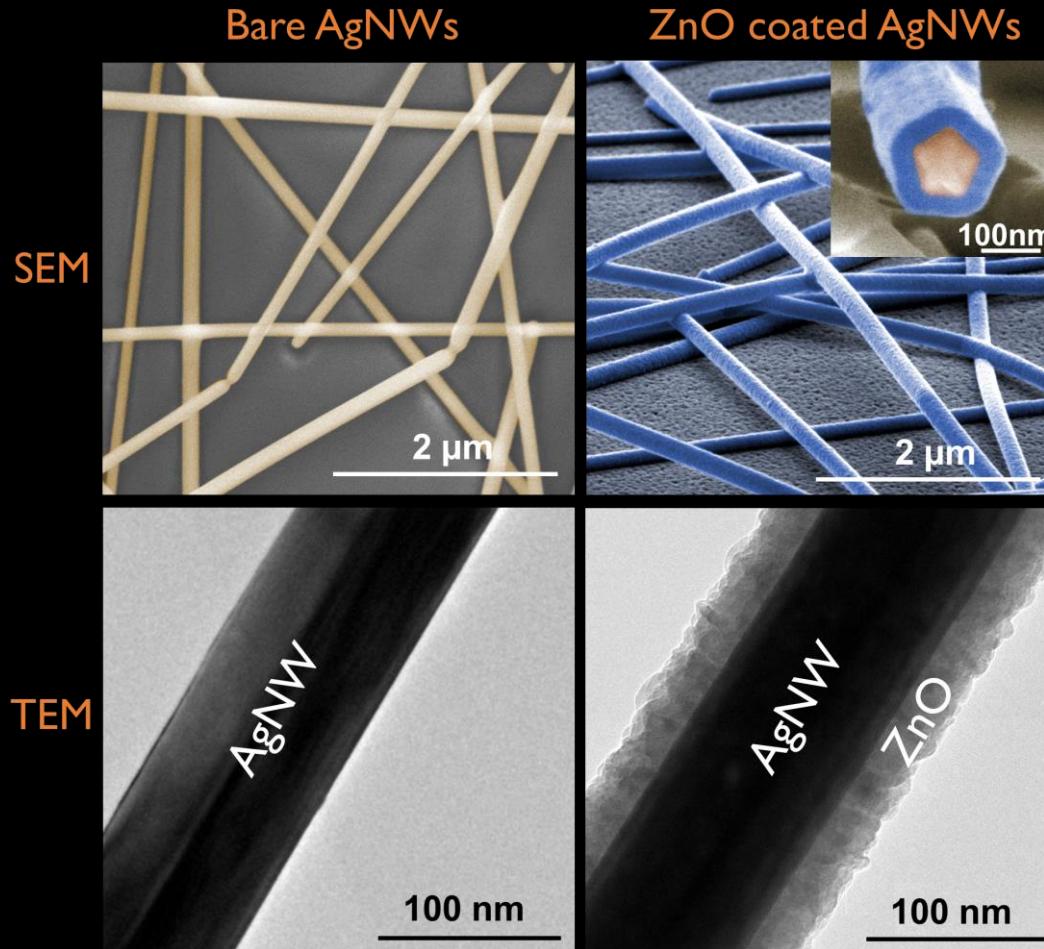
AP-SALD @ LMGP

Ag Nanowires
Spray Deposition



Study of the effect of ZnO coating thickness on stability

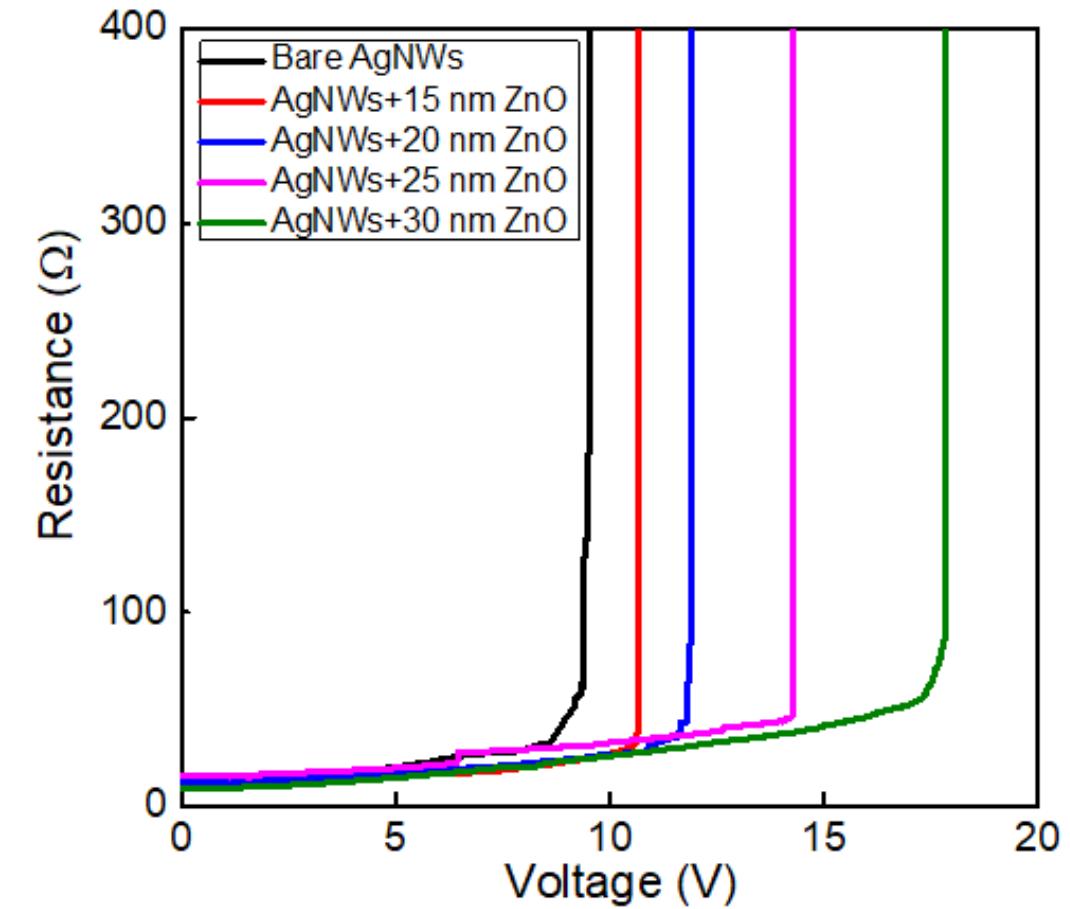
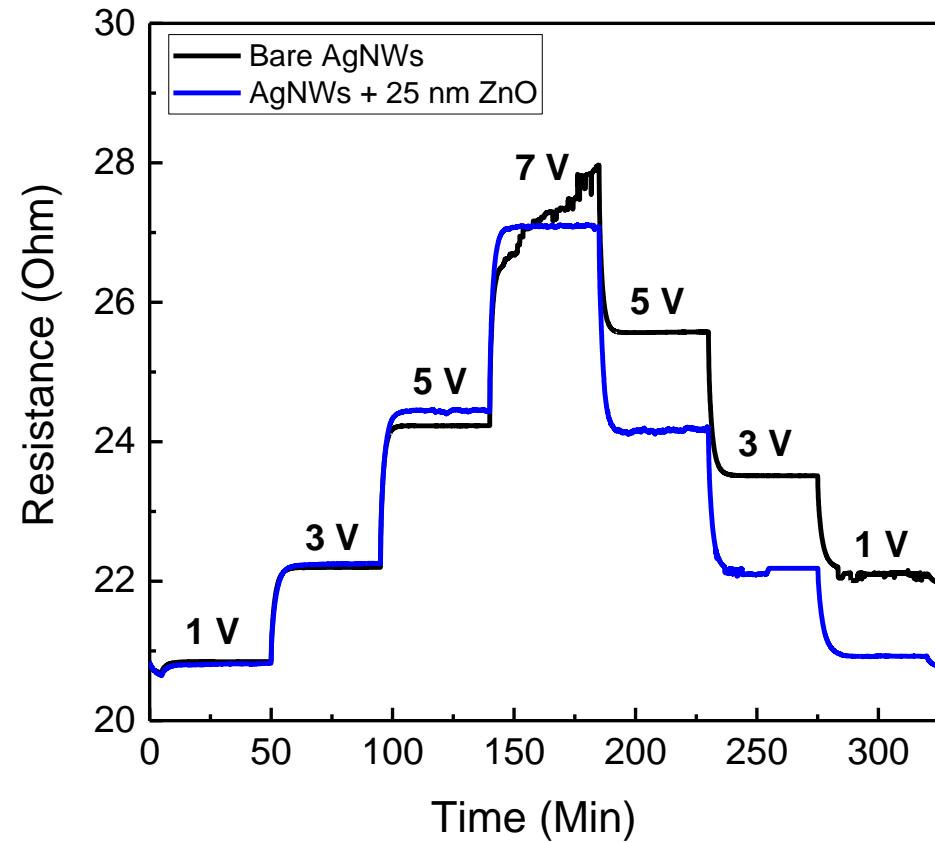
DEZ + H₂O, 200 °C



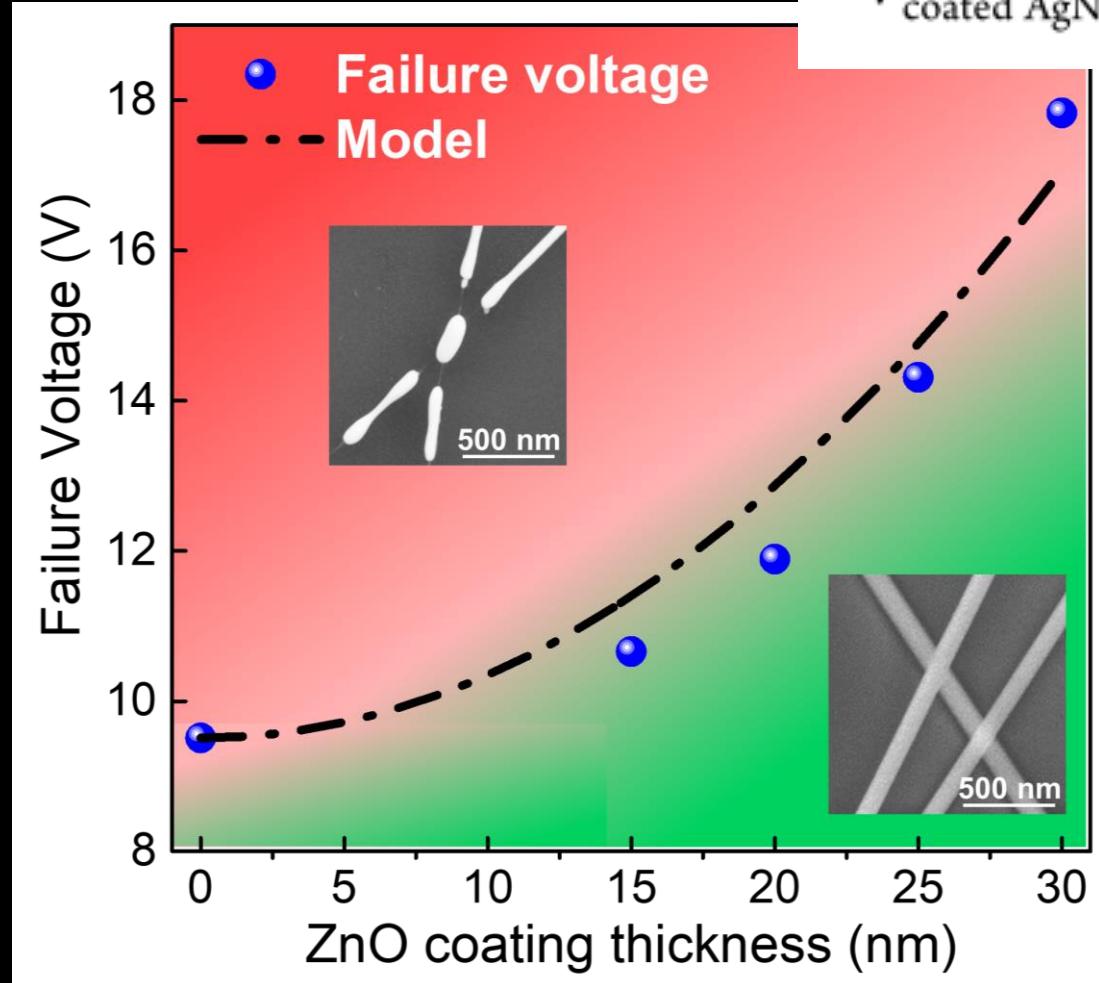
Study of the effect of ZnO coating thickness on stability



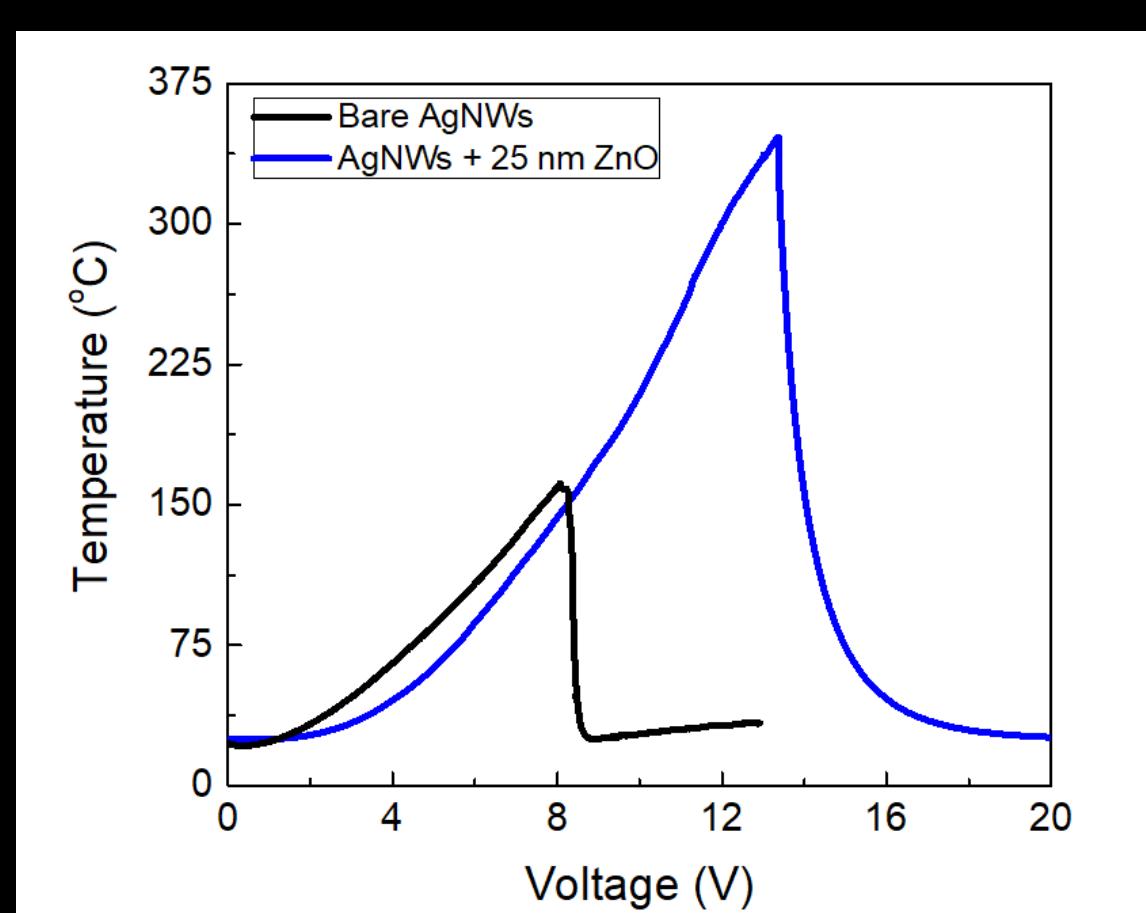
Failure upon thermal ramp increases for thicker coatings



Study of the effect of ZnO coating thickness on stability



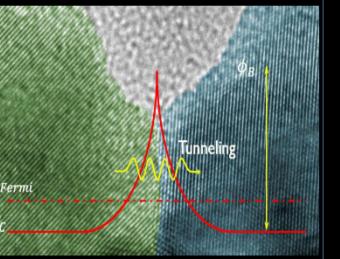
$$V_{\text{coated AgNW}}^{\text{fail}}(L_{\text{ZnO}}) = V_{\text{bare AgNW}}^{\text{fail}} + \frac{\dot{V} \cdot L_{\text{ZnO}}^2}{2D}$$



Laboratoire des Matériaux et du Génie Physique (Grenoble-INP/CNRS); david.munoz-rojas@grenoble-inp.fr

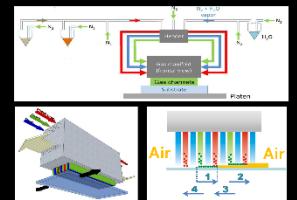
Abstract

Transparent conductive oxides (TCOs) are key components of optoelectronic devices, such as solar cells or LEDs. TCOs, and in general all highly doped polycrystalline semiconductors, present high potential barriers and short depletion layers at the grain boundaries. This results in an increased probability of electron tunneling through the grain boundaries, as opposed to the thermionic emission mechanism observed in low doping semiconductors. Existing conductivity models do not properly account for charge tunneling through the grain boundaries in TCOs, which prevents a proper understanding of the scattering mechanisms limiting their conductivity. We present a new model based on the Airy Function Transfer Matrix Method that allows the numerical calculation of charge mobility through grain boundaries in highly doped polycrystalline semiconductors. The new model has been used to fit experimental data obtained for Aluminum doped ZnO (AZO) samples synthesized by different methods. This has allowed the calculation of the electron trap density at grain boundaries, thus providing the dominant charge scattering mechanisms for the different samples. Our findings show that **AZO films deposited by atm. methods (such as spatial atomic layer deposition, SALD) suffer from a high trap density of traps at the grain boundaries, which limits the mobility in these films.** UV light can be used to improve the mobility by releasing trapped oxygen, and the desorption curves can be used as a simple way to obtain the trap density at the grain boundaries.



AZO deposition by SALD: open air processing, how does it compare to other deposition techniques?

Spatial Atomic Layer deposition: Separation of precursors in space, ALD done at high throughput in the open air.

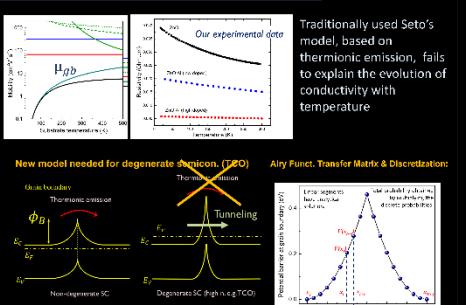


Technique	T °C	t (nm)	μ (cm²V⁻¹s⁻¹)	N (cm⁻³)	p [cm]
PLD	230	280	47.6	1.54×10^{21}	8.54×10^{-5}
DC Sputt.	RT	350	14.8	8.2×10^{20}	3.5×10^{-4}
RF Sputt.	100	680	28	5.9×10^{20}	3.7×10^{-4}
MOCVD	450	600	17	4.35×10^{20}	8.35×10^{-4}
ALD	300	200	19.7	2.2×10^{20}	1.4×10^{-3}
SALD-TNO	200	320	5	5.0×10^{20}	2.0×10^{-3}
SALD-LMGP	200	210	2.6	4.25×10^{20}	5.6×10^{-3}

Mobility highly affected by oxygen pressure

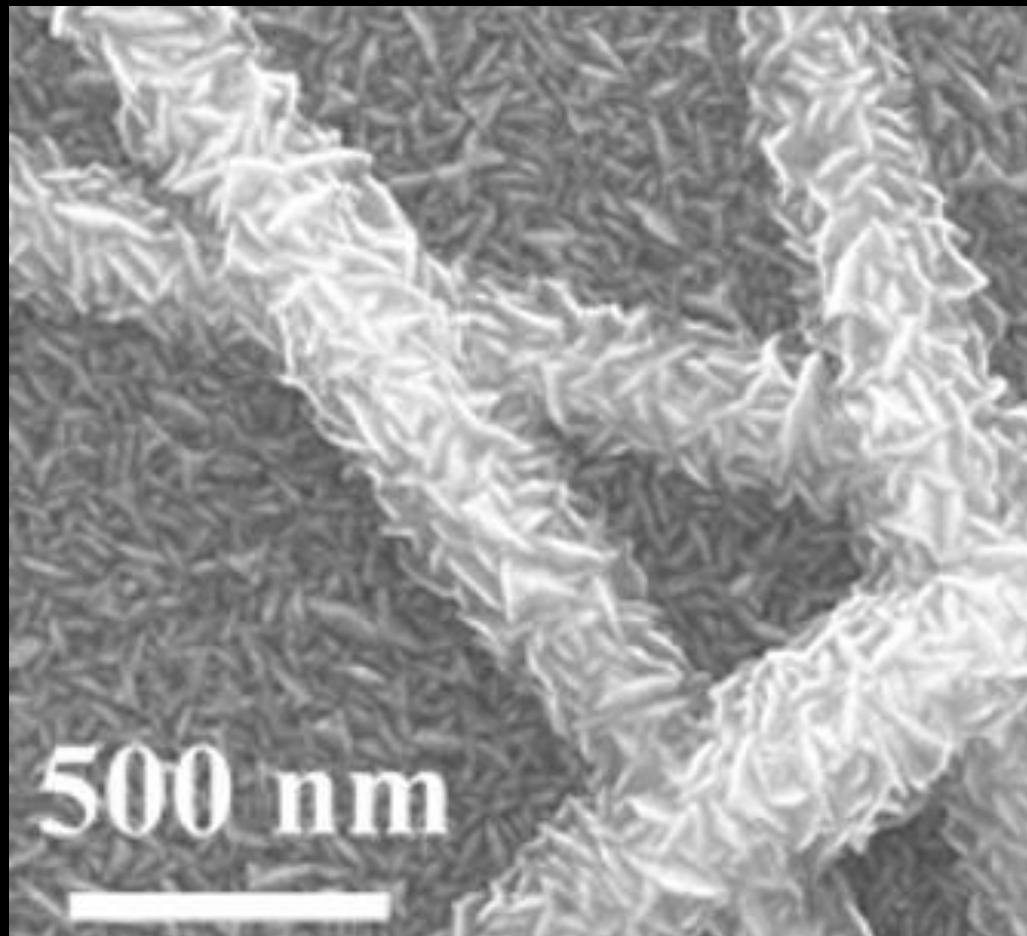
Oxygen pressure increasing

New model: tunnelling included



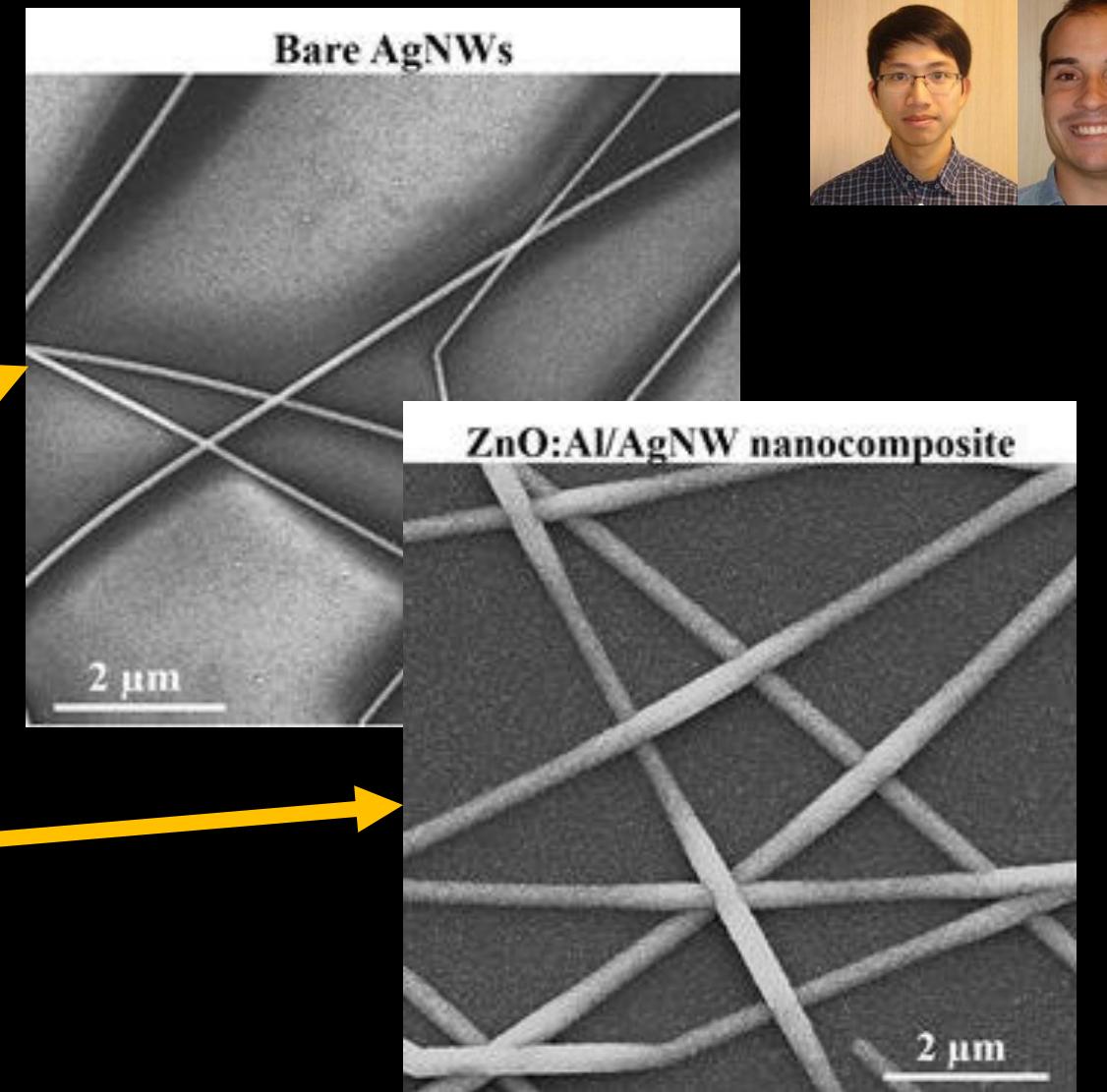
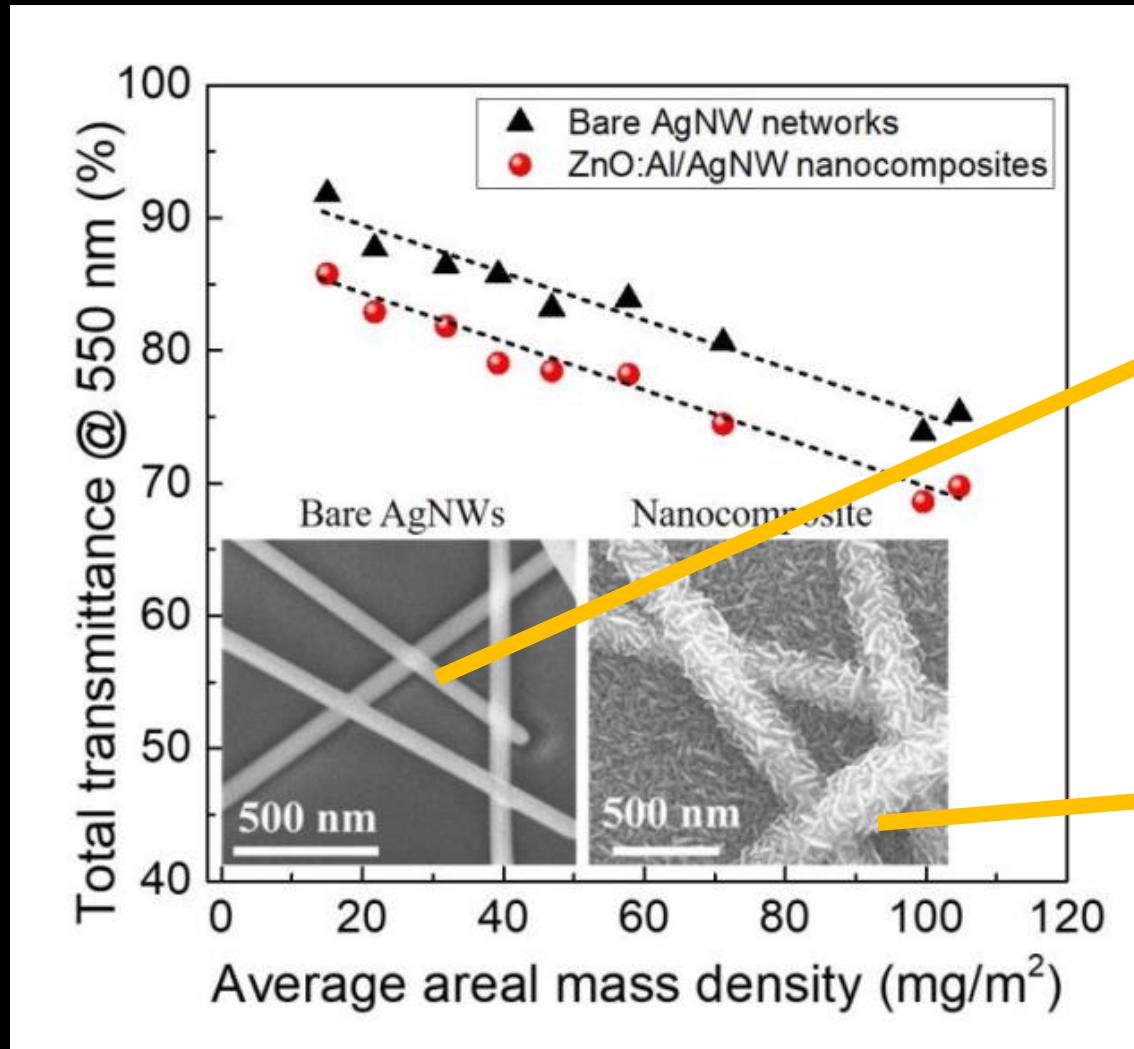
New model predicts diff. behav. depending on which is the most important scattering factor. Our AZO is Type III, i.e. GB limited

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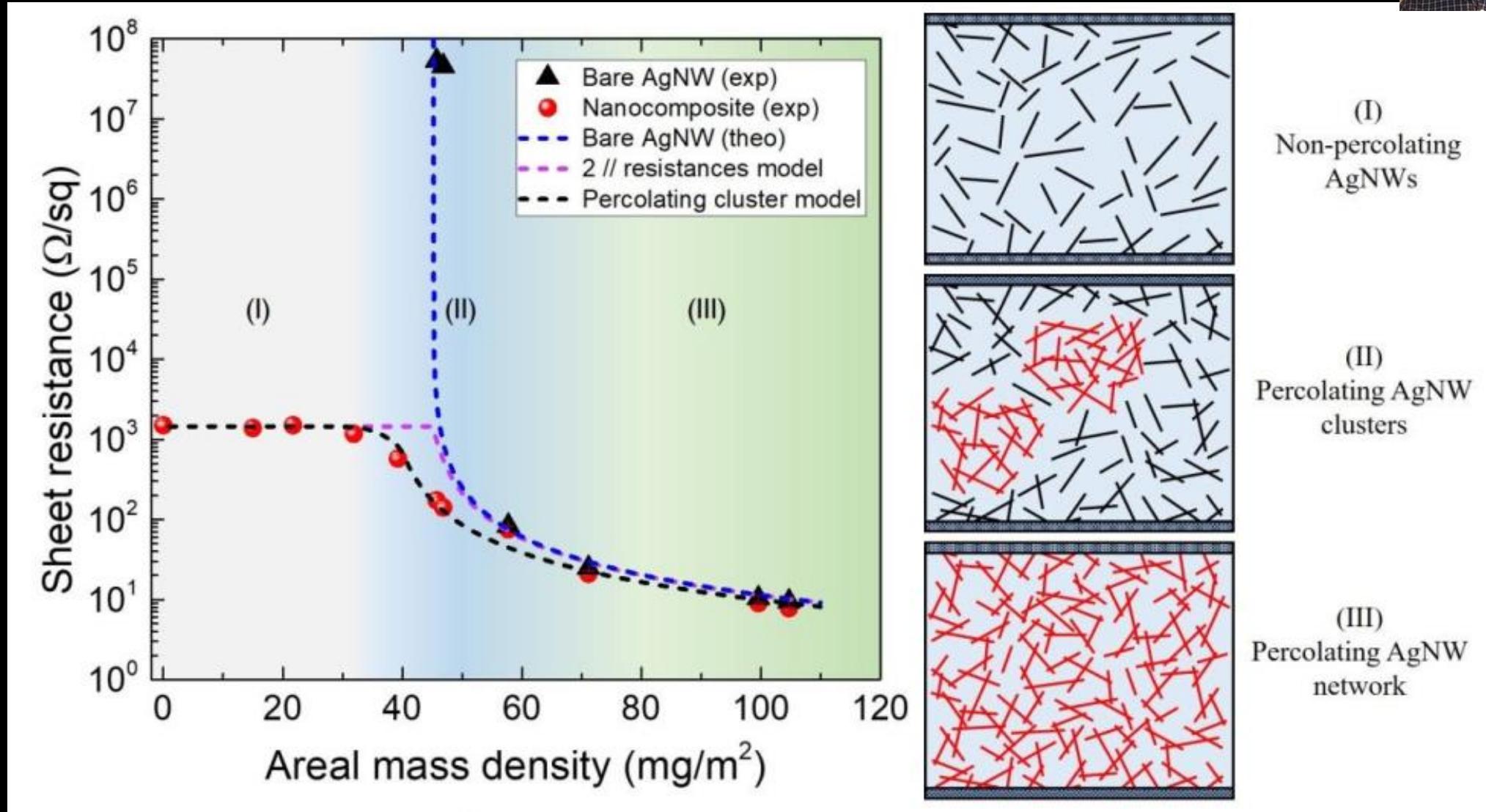
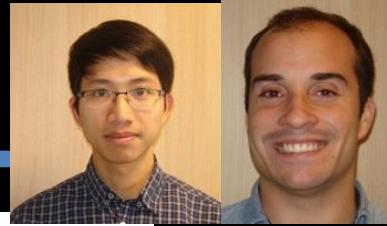


**AgNWs + Al:ZnO by AP-SALD
DEZ, TMA, H₂O, 200 °C, 150 nm**

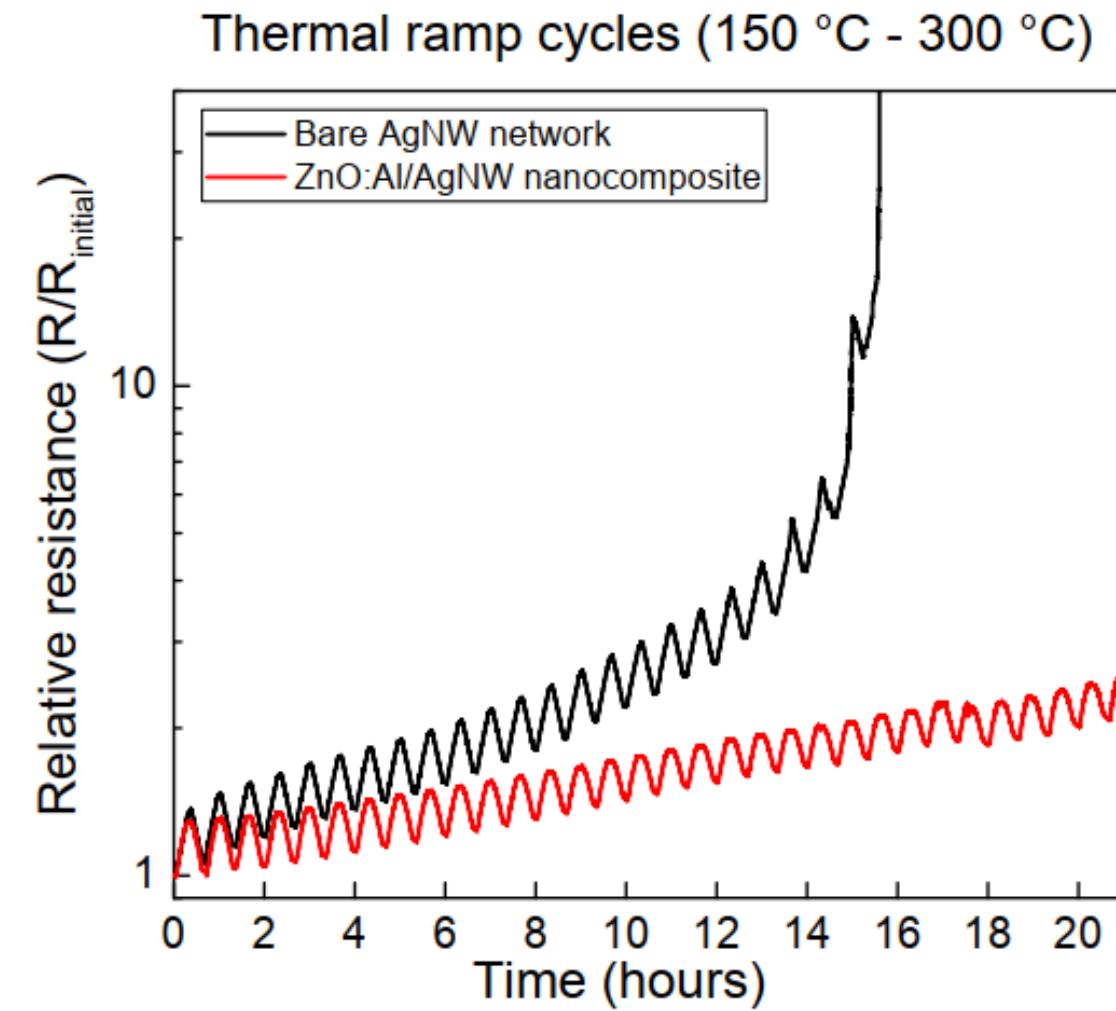
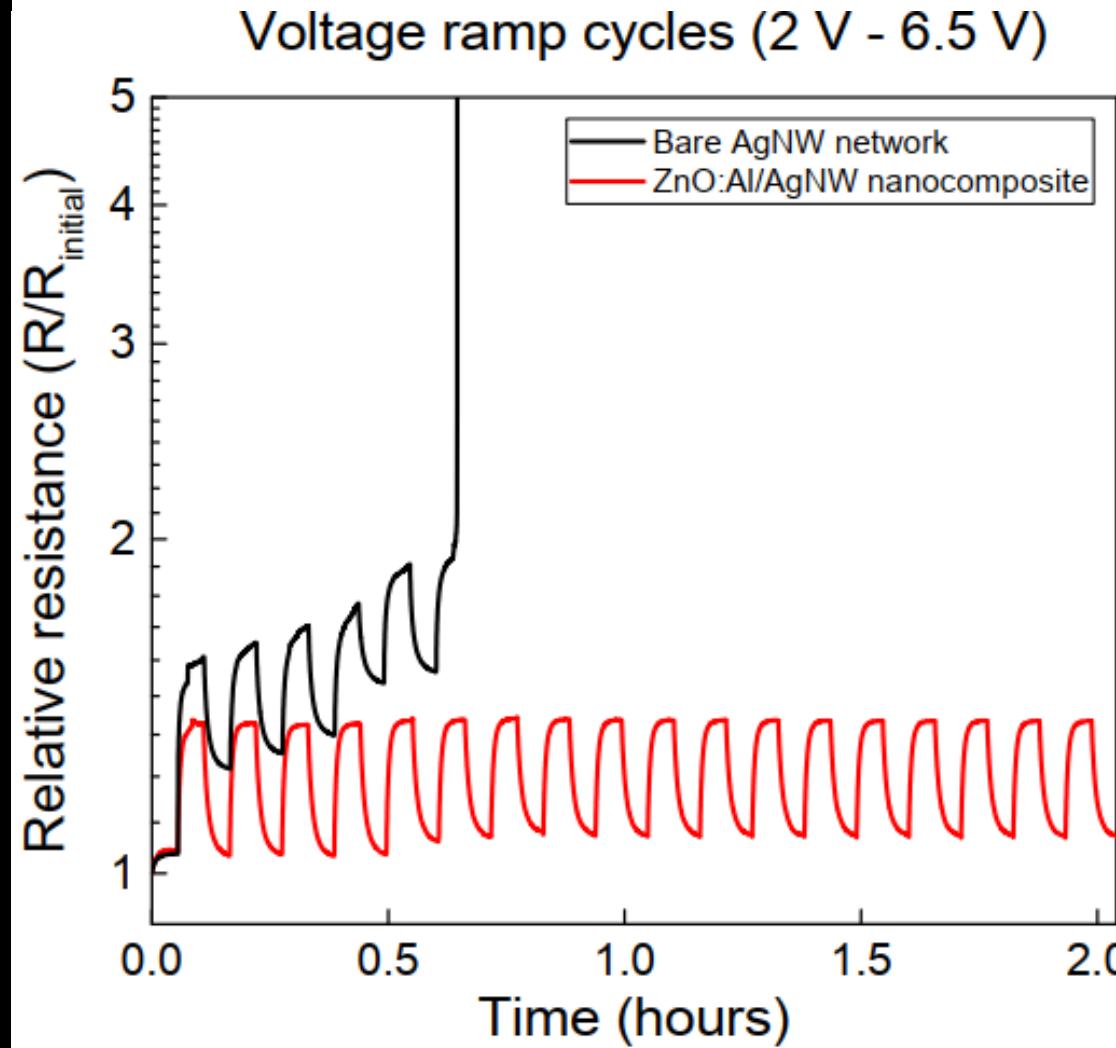
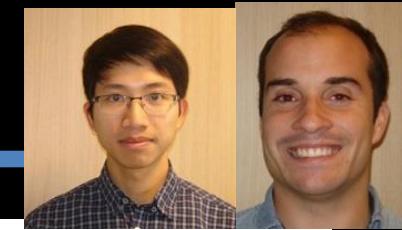
AgNW networks + TCO coating: better collection eff.



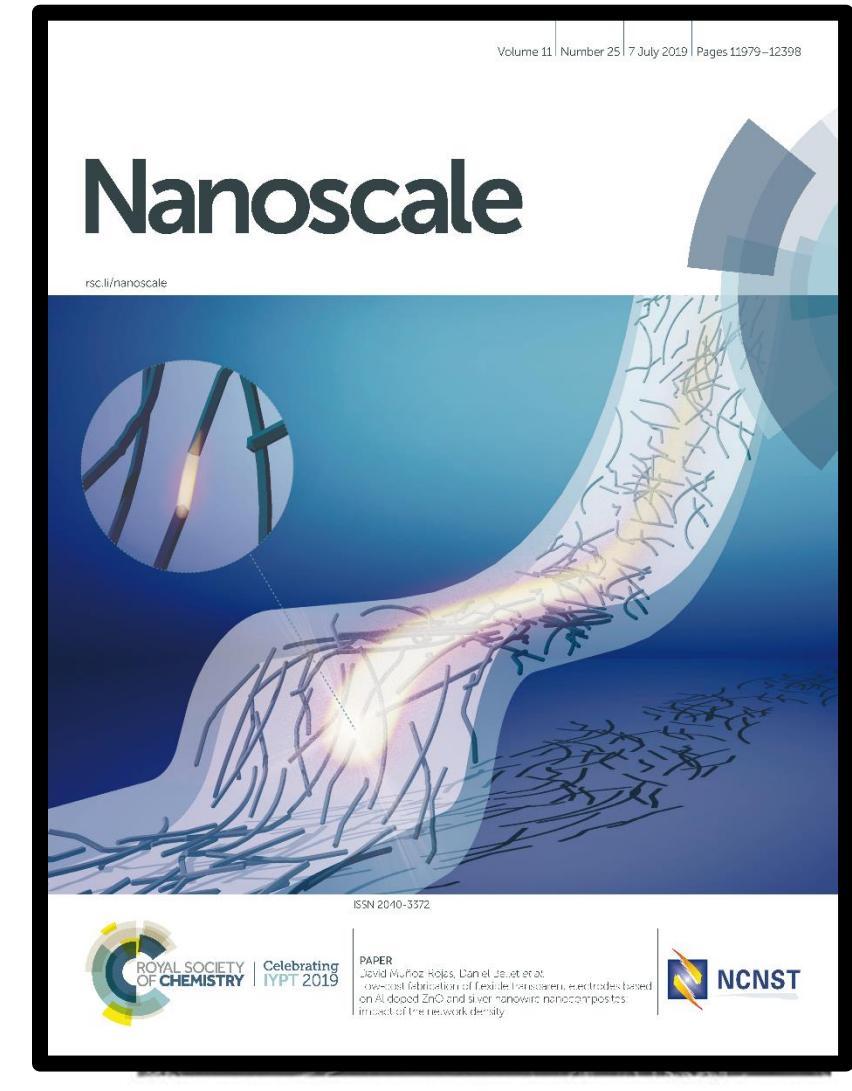
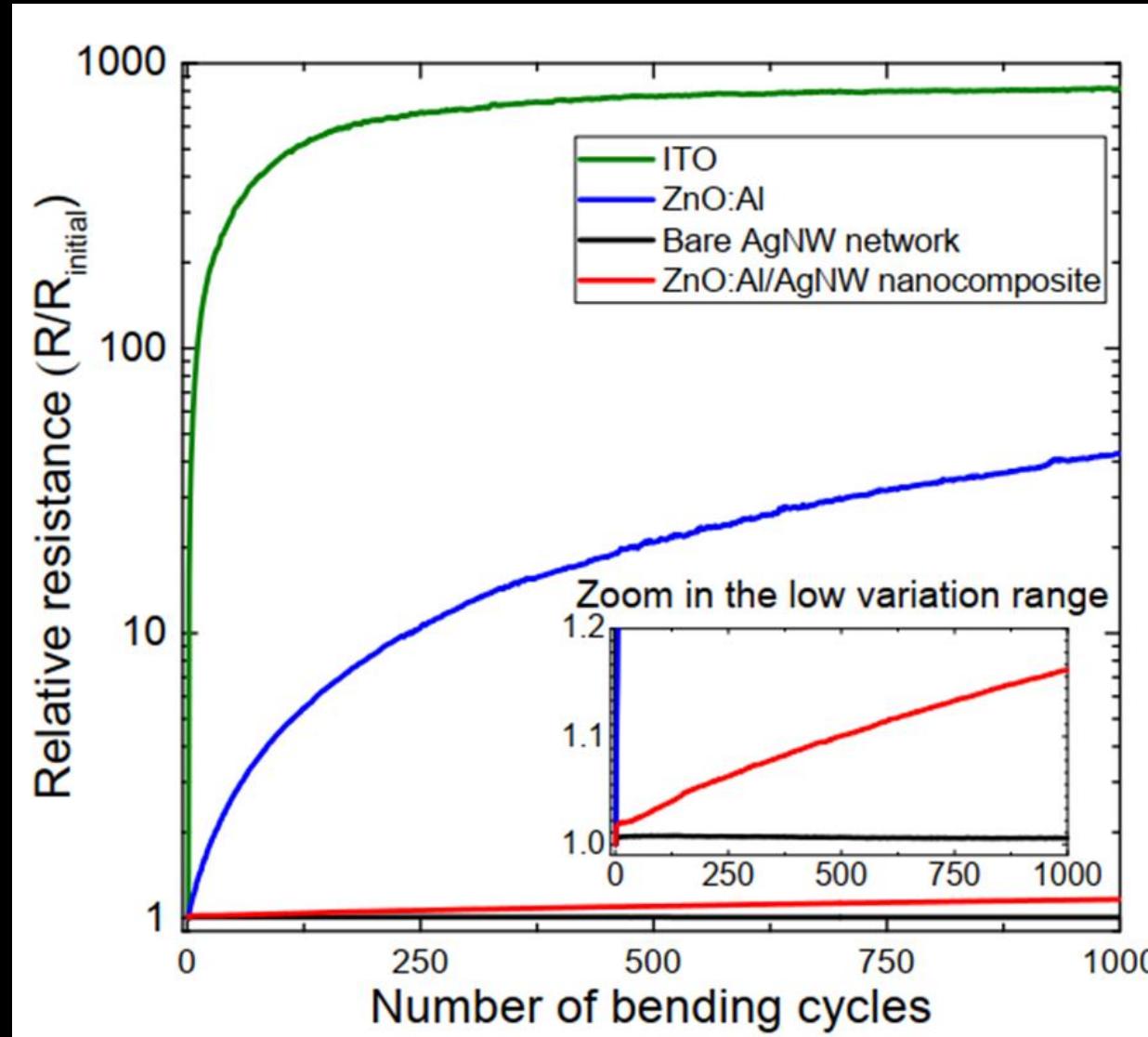
Synergistic effect for low AgNWs areal densities



More stable than bare AgNW networks



More flexible than bare AgNW networks or Al:ZnO



Conclusions

- ***AP-SALD: protective conformal coatings and nanocomposites for AgNW based electrodes: thermal, electrical, chemical and mechanical stability improvement***
- ***Also protection of CuNW networks (with Al₂O₃, Celle, C. et al. Nanotechnology, 29 (2018) 085701)***
- ***Coatings & composites contribute to a fundamental understanding of the stability and behavior of AgNWs***



Announcements!

LATE NEWS-HOT TOPIC Abstracts
on September 4 – 18th 11:59 ET



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Symposium FF05—Advanced Atomic Layer Deposition and Chemical Vapor Deposition Techniques and Applications

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david.munoz-rojas@grenoble-inp.fr



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Thanks for your attention!!!



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